# RT1P44QX SERIES

**(Transistor)** 

Transistor With Resistor
For Switching Application
Silicon PNP Epitaxial Type

# **DESCRIPTION**

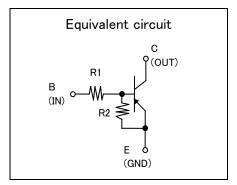
RT1P44QX is a one chip transistor with built-in bias resistor, NPN type is RT1N44QX.

## **FEATURE**

•Built-in bias resistor (R1=47k  $\Omega$  ,R2=10k  $\Omega$  ).

# **APPLICATION**

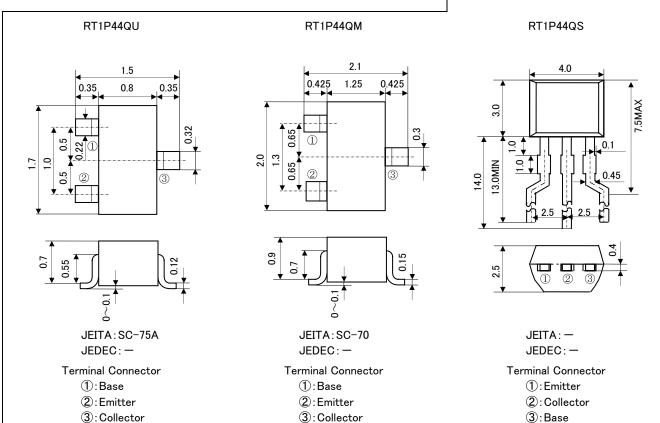
Inverted circuit, switching circuit, interface circuit, driver circuit.



# OUTLINE DRAWING UNIT:mm RT1P44QC 2.8 0.65 1.5 0.65 3 JEITA: SC-59

JEDEC: Similar to TO-236

Terminal Connector
①: Base
②: Emitter
③: Collector

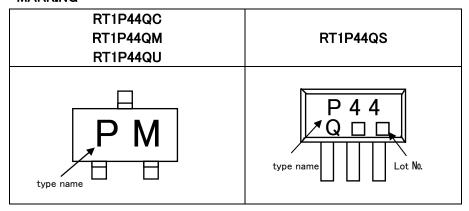


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# **MARKING**



# MAXIMUM RATING (Ta=25°C)

SYMBOL	PARAMETER	RATING				
		RT1P44QU	RT1P44QM	RT1P44QC	RT1P44QS	UNIT
$V_{CBO}$	Collector to Base voltage	-50				
$V_{EBO}$	Emitter to Base voltage	-15				
$V_{CEO}$	Collector to Emitter voltage	-50				
$V_{IN}$	Input voltage	-40				
Ic	Collector current	-100				
I <sub>CM</sub>	Peak Collector current	-200				
P <sub>C</sub>	Collector dissipation(Ta=25°C)	150	20	00	450	mW
Tj	Junction temperature	+150				°C
Tstg	Storage temperature	−55 <b>~</b> +150				°C

# ELECTRICAL CHARACTERISTICS (Ta=25°C)

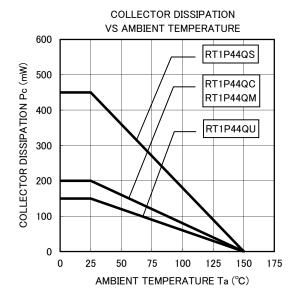
SYMBOL	PARAMETER	TEST CONDITION	LIMIT			UNIT
		TEST CONDITION	MIN	TYP	MAX	UNIT
$V_{(BR)CEO}$	C to E breakdown voltage	$I_{C}=-100 \mu A, R_{BE}=\infty$	-50	_	1	V
I <sub>CBO</sub>	Collector cut off current	$V_{CB}$ =-50V, I $_{E}$ =0	_	_	-0.1	μΑ
I <sub>EBO</sub>	Emitter cut off current	$V_{EB}$ =-5V, I $_{C}$ =0	-66	-88	-127	μΑ
h <sub>FE</sub>	DC forward current gain	$V_{CE}$ =-5V, I <sub>C</sub> =-5mA	33	_	ı	_
$V_{CE(sat)}$	C to E saturation voltage	$I_{C} = -10 \text{mA}, I_{B} = -0.5 \text{mA}$	1	_	-0.3	V
$V_{I(ON)}$	Input on voltage	$V_{CE}$ =-0.2V, I $_{C}$ =-5mA	1	-4.2	-8.9	V
$V_{I(OFF)}$	Input off voltage	$V_{CE} = -5V$ , I $_{C} = -100 \mu$ A	-2.3	-3.1	ı	V
R <sub>1</sub>	Input resistor	_	33	47	61	kΩ
R <sub>2</sub> /R <sub>1</sub>	Resistor ratio	_	0.17	0.21	0.26	_
$f_T$	Gain band width product	$V_{CE}$ =-6V, I <sub>E</sub> =10mA	_	150	_	MHz

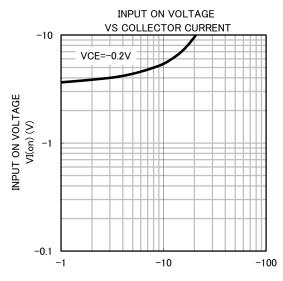
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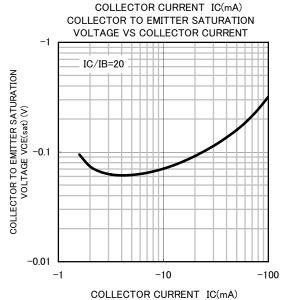
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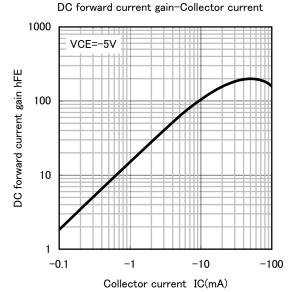
Transistor With Resistor For Switching Application Silicon PNP Epitaxial Type

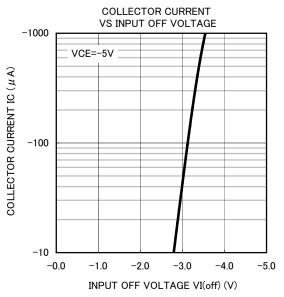
# TYPICAL CHARACTERISTICS (Ta=25°C)











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